

# JUNCTION FIELD EFFECT TRANSISTOR 2SK2552

# N-CHANNEL SILICON JUNCTION FIELD EFFECT TRANSISTOR FOR IMPEDANCE CONVERTER OF ECM

#### **DESCRIPTION**

The 2SK2552 is suitable for converter of ECM.

#### **FEATURES**

- · Compact package
- High forward transfer admittance 1000  $\mu$ S TYP. (lbss = 100  $\mu$ A) 1600  $\mu$ S TYP. (lbss = 200  $\mu$ A)
- Includes diode and high resistance at G S

#### ORDERING INFORMATION

PART NUMBER	PACKAGE		
2SK2552	SC-75 (USM)		

#### ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage Note 1	VDSX	20	V
Gate to Drain Voltage	Vgdo	-20	V
Drain Current	lσ	10	mΑ
Gate Current	lg	10	mΑ
Total Power Dissipation Note2	PT	200	mW
Junction Temperature	$T_j$	125	°C
Storage Temperature	Tstg	-55 to +125	°C

## **EQUIVALENT CIRCUIT**

PACKAGE DRAWING (Unit: mm)

 $0.1^{+0.1}_{-0.05}$ 

0 to 0.1

0.6

 $0.75 \pm 0.05$ 

 $0.3 \pm 0.05$ 

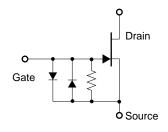
G

 $0.2^{+0.1}_{-0}$ 

0.5

1.0 1.6 ± 0.1

 $1.6 \pm 0.1$  $0.8 \pm 0.1$ 



**Notes 1.** Vgs = -1.0 V

2. Mounted on ceramic substrate of 3.0 cm<sup>2</sup> x 0.64 mm

Remark Please take care of ESD (Electro Static Discharge) when you handle the device in this document.

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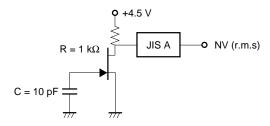
# **ELECTRICAL CHARACTERISTICS (TA = 25°C)**

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Cut-off Current	loss	V <sub>DS</sub> = 5.0 V, V <sub>GS</sub> = 0 V	40		600	μΑ
Gate Cut-off Voltage	V <sub>GS(off)</sub>	$V_{DS} = 5.0  \text{V},  I_{D} = 1.0  \mu\text{A}$	-0.1		-1.0	٧
Forward Transfer Admittance	<b>y</b> fs1	$V_{DS} = 5.0 \text{ V}, \text{ ID} = 30 \ \mu\text{A}, \text{ f} = 1.0 \text{ kHz}$	350			μS
Forward Transfer Admittance	<b>y</b> fs2	$V_{DS} = 5.0  V,  V_{GS} = 0  V,  f = 1.0  kHz$	350			μS
Input Capacitance	Ciss	V <sub>DS</sub> = 5.0 V, V <sub>GS</sub> = 0 V, f = 1.0 MHz		7.0	8.0	pF
Noise Voltage	NV	See Test Circuit		1.8	3.0	μV

# IDSS RANK

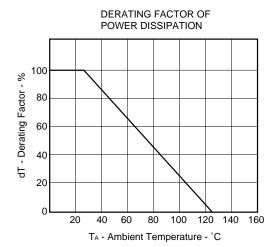
MARKING	J2	J3	J4	J5	J6	J7
loss (μA)	40 to 70	60 to 110	90 to 180	150 to 300	200 to 450	300 to 600

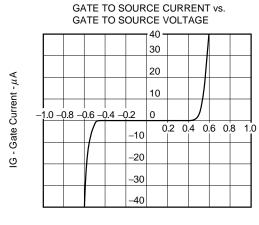
# **NOISE VOLTAGE TEST CIRCUIT**



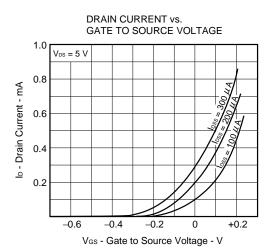


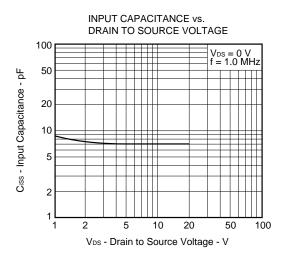
### TYPICAL CHARACTERISTICS (TA = 25°C)



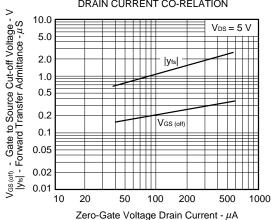


V<sub>GS</sub> - Gate to Source Voltage - V





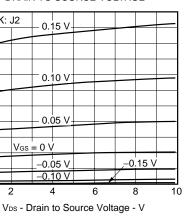
GATE TO SOURCE CUT-OFF VOLTAGE AND FORWARD TRANSFER ADMITTANCE vs. ZERO-GATE VOLTAGE DRAIN CURRENT CO-RELATION

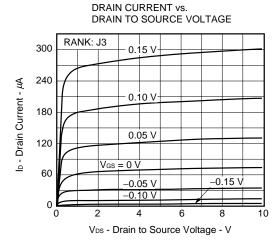


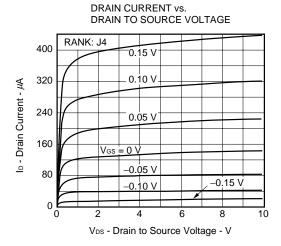
Data Sheet D15941EJ1V0DS 3

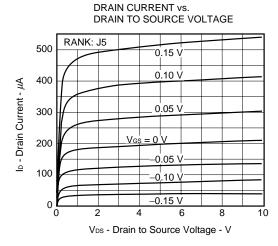
#### DRAIN TO SOURCE VOLTAGE RANK: J2 250 0.15 V 200 I<sub>D</sub> - Drain Current - μA 0.10 V 150 0.05 V 100 $V_{GS} = 0 V$ 50 <u>-0.15</u> V -0.05 V\_ –0.10 V 0 0 8

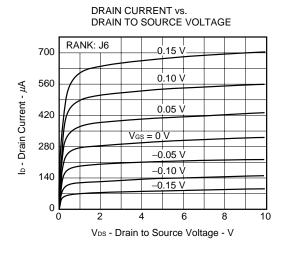
DRAIN CURRENT vs.

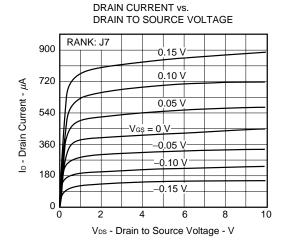












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